

Rectifier Diode

Types W1263Y#160 to W1263Y#250

Old Type No.: SW02-25CXC565

Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{RRM}	Repetitive peak reverse voltage, (note 1)	1600-2500	V
V_{RSM}	Non-repetitive peak reverse voltage, (note 1)	1700-2600	V

	OTHER RATINGS	MAXIMUM LIMITS	UNITS
$I_{F(AV)M}$	Maximum average forward current, $T_{sink}=55^{\circ}C$, (note 2)	1263	A
$I_{F(AV)M}$	Maximum average forward current, $T_{sink}=100^{\circ}C$, (note 2)	923	A
$I_{F(AV)M}$	Maximum average forward current, $T_{sink}=100^{\circ}C$, (note 3)	563	A
$I_{F(RMS)M}$	Nominal RMS forward current, $T_{sink}=25^{\circ}C$, (note 2)	2289	A
$I_{F(d.c.)}$	D.C. forward current, $T_{sink}=25^{\circ}C$, (note 4)	1972	A
I_{FSM}	Peak non-repetitive surge $t_p=10ms$, $V_{rm}=60\%V_{RRM}$, (note 5)	11.7	kA
I_{FSM2}	Peak non-repetitive surge $t_p=10ms$, $V_{rm}\leq 10V$, (note 5)	12.9	kA
I^2t	I^2t capacity for fusing $t_p=10ms$, $V_{rm}=60\%V_{RRM}$, (note 5)	684×10^3	A^2s
I^2t	I^2t capacity for fusing $t_p=10ms$, $V_{rm}\leq 10V$, (note 5)	828×10^3	A^2s
$T_{j\ op}$	Operating temperature range	-40 to +175	$^{\circ}C$
T_{stg}	Storage temperature range	-40 to +200	$^{\circ}C$

Notes:-

- 1) De-rating factor of 0.13% per $^{\circ}C$ is applicable for T_j below $25^{\circ}C$.
- 2) Double side cooled, single phase; 50Hz, 180° half-sinewave.
- 3) Single side cooled, single phase; 50Hz, 180° half-sinewave.
- 4) Double side cooled.
- 5) Half-sinewave, $175^{\circ}C$ T_j initial.

Characteristics

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
V _{FM}	Maximum peak forward voltage	-	-	2.12	I _{TM} =3770A	V
V _{T0}	Threshold voltage	-	-	0.87		V
r _T	Slope resistance	-	-	0.33		mΩ
I _{RRM}	Peak reverse current	-	-	30	Rated V _{RRM}	mA
I _{RRM}	Peak reverse current	-	-	30	Rated V _{RRM} , T _j =25°C	mA
Q _{rr}	Recovered charge	-	1300	-	I _{TM} =500A, t _p =500μs, di/dt=10A/μs, V _r =50V	μC
Q _{ra}	Recovered charge, 50% Chord	-	850	1150		μC
I _{rr}	Reverse recovery current	-	100	-		A
t _{rr}	Reverse recovery time	-	17	-		μs
R _{thJK}	Thermal resistance, junction to heatsink	-	-	0.05	Double side cooled	K/W
		-	-	0.10	Single side cooled	K/W
F	Mounting force	5.5	-	8.3		kN
W _t	Weight	-	90	-	Housing option YC	g
		-	140	-	Housing option YH	

Notes:-

1) Unless otherwise indicated T_j=175°C.

Notes on Ratings and Characteristics**1.0 Voltage Grade Table**

Voltage Grade	V_{DRM} V_{DSM} V_{RRM} V	V_{RSM} V	V_D V_R DC V
16	1600	1700	1050
18	1800	1900	1150
20	2000	2100	1250
22	2200	2300	1350
24	2400	2500	1450
25	2500	2600	1500

2.0 Extension of Voltage Grades

This report is applicable to other voltage grades when supply has been agreed by Sales/Production.

3.0 De-rating Factor

A blocking voltage de-rating factor of 0.13%/°C is applicable to this device for T_j below 25°C.

4.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor or excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

5.0 Computer Modelling Parameters**5.1 Device Dissipation Calculations**

$$I_{AV} = \frac{-V_{T0} + \sqrt{V_{T0}^2 + 4 \cdot ff^2 \cdot r_T \cdot W_{AV}}}{2 \cdot ff^2 \cdot r_T} \quad \text{and:} \quad W_{AV} = \frac{\Delta T}{R_{th}}$$

$$\Delta T = T_{jmax} - T_K$$

Where $V_{T0}=0.87V$, $r_T=0.33m\Omega$,

R_{th} = Supplementary thermal impedance, see table below and

ff = Form factor, see table below.

Supplementary Thermal Impedance				
Conduction Angle	6 Phase (60°)	3 Phase (120°)	½ Wave (180°)	d.c.
Square wave Double Side Cooled	0.069	0.061	0.057	0.05
Square wave Single Side Cooled	0.119	0.111	0.107	0.1
Sine wave Double Side Cooled	0.052	0.0513	0.0505	
Sine wave Single Side Cooled	0.102	0.1013	0.1005	

Form Factors				
Conduction Angle	6 Phase (60°)	3 Phase (120°)	½ Wave (180°)	d.c.
Square wave	2.449	1.732	1.414	1
Sine wave	2.778	1.879	1.57	

5.2 Calculating V_F using ABCD Coefficients

The on-state characteristic I_F vs. V_F , on page 6 is represented in two ways;

- (i) the well established V_{T0} and r_F tangent used for rating purposes and
- (ii) a set of constants A, B, C, D, forming the coefficients of the representative equation for V_F in terms of I_F given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given below for both hot and cold characteristics. The resulting values for V_F agree with the true device characteristic over a current range, which is limited to that plotted.

	25°C Coefficients	175°C Coefficients
A	0.988190696	0.322649754
B	-0.02390475	0.08667911
C	1.37558×10^{-4}	2.61136×10^{-4}
D	0.01055999	1.61365×10^{-3}

5.3 D.C. Thermal Impedance Calculation

$$r_t = \sum_{p=1}^{p=n} r_p \cdot \left(1 - e^{\frac{-t}{\tau_p}} \right)$$

Where $p = 1$ to n , n is the number of terms in the series and:

t = Duration of heating pulse in seconds.

r_t = Thermal resistance at time t .

r_p = Amplitude of p_{th} term.

τ_p = Time Constant of r_{th} term.

The coefficients for this device are shown in the tables below:

D.C. Single Side Cooled					
Term	1	2	3	4	5
r_p	0.06158	8.43118×10^{-3}	0.01031	0.01614	5.0391×10^{-3}
τ_p	2.13613	1.2129	0.15024	0.04244	3.6777×10^{-3}

D.C. Double Side Cooled				
Term	1	2	3	4
r_p	0.02	9.9234×10^{-3}	0.01434	4.284×10^{-3}
τ_p	0.33917	0.12691	0.03562	2.563×10^{-3}

6.0 Reverse recovery ratings

(i) Q_{rr} is based on 50% I_{RM} chord as shown in Fig. 1

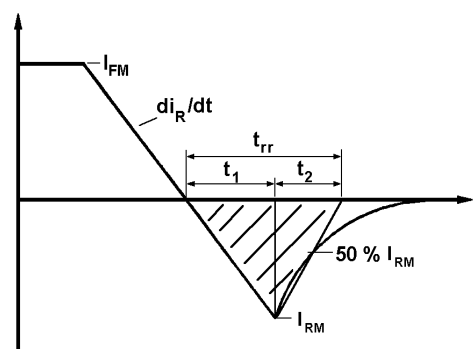


Fig. 1

(ii) Q_{rr} is based on a 150 μ s integration time i.e.

$$Q_{rr} = \int_0^{150\mu s} i_{rr} \cdot dt$$

(iii)

$$K \text{ Factor} = \frac{t_1}{t_2}$$

Curves

Figure 1 - Forward characteristics of Limit device

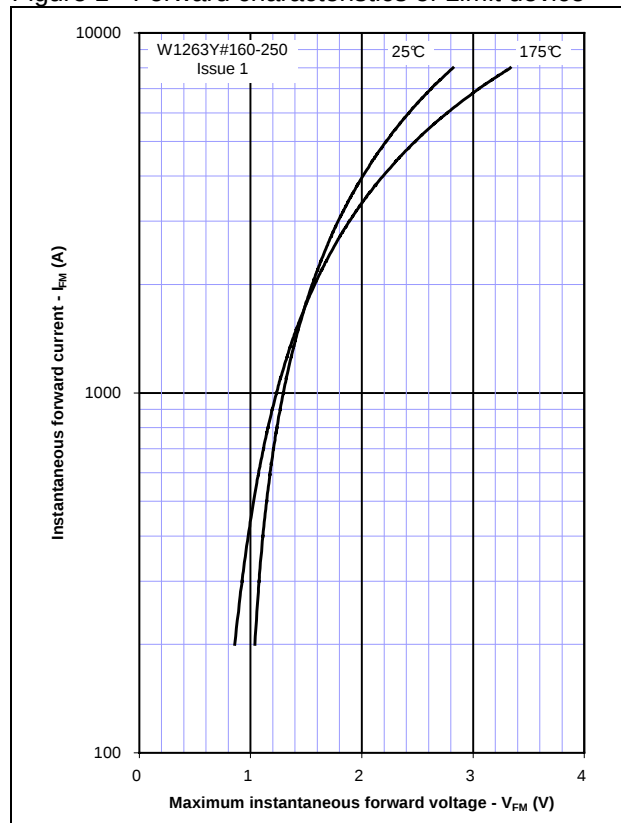


Figure 2 - Transient thermal impedance

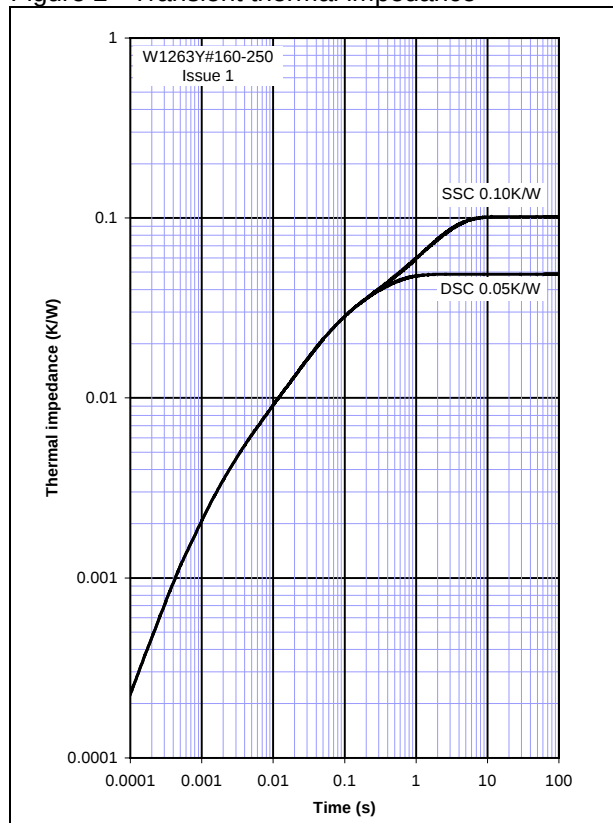


Figure 3 - Maximum surge Rating

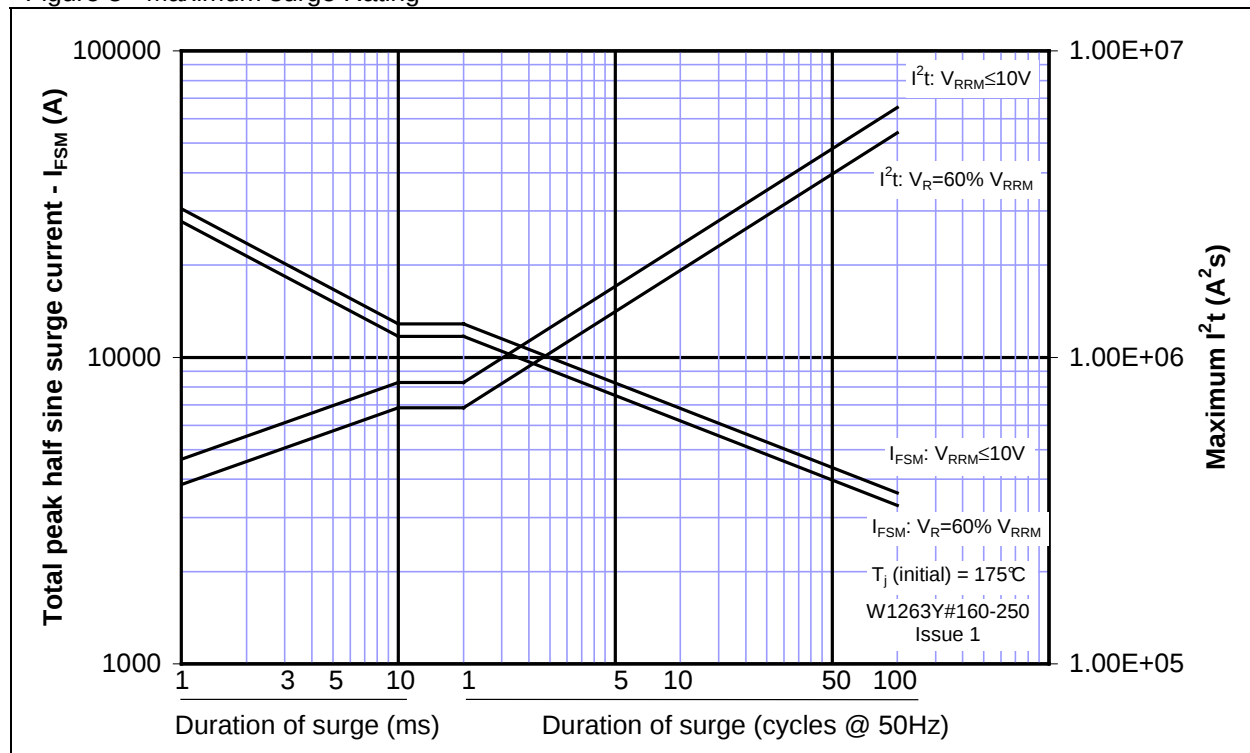


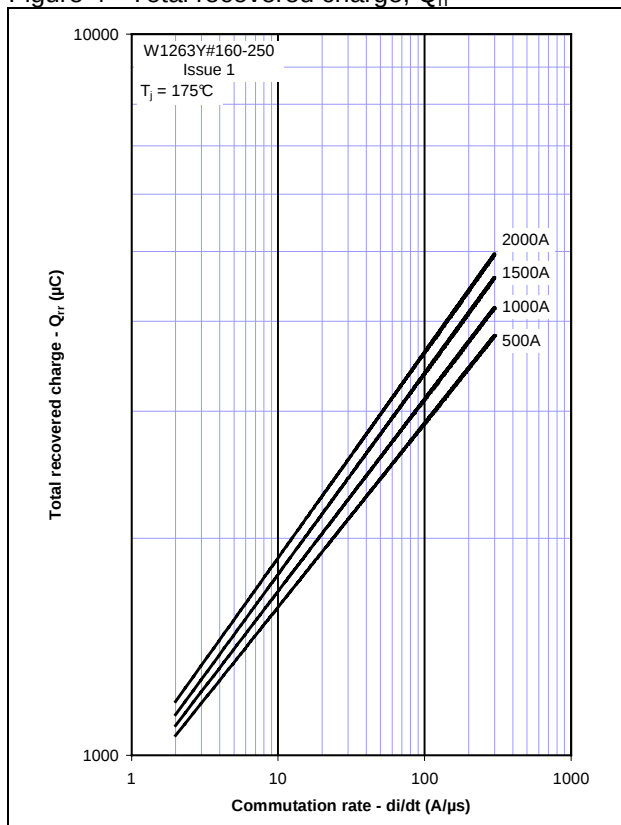
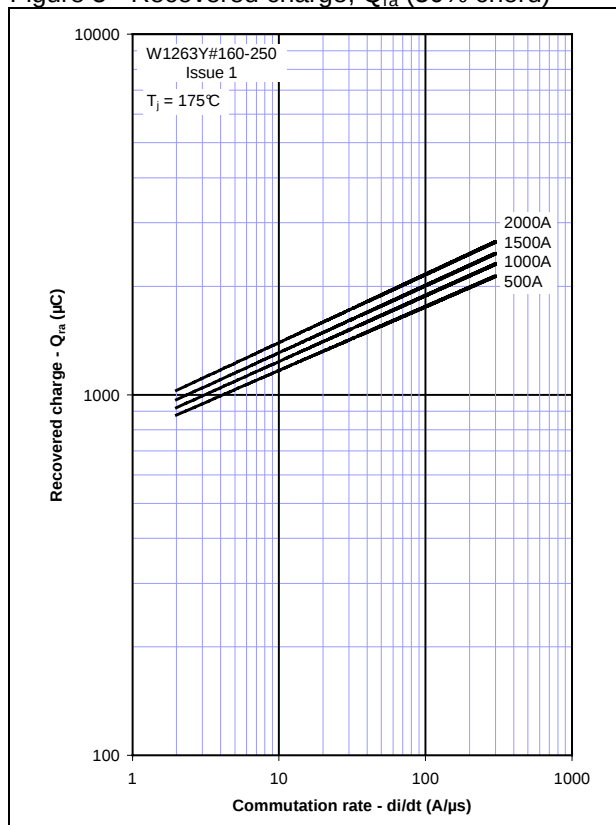
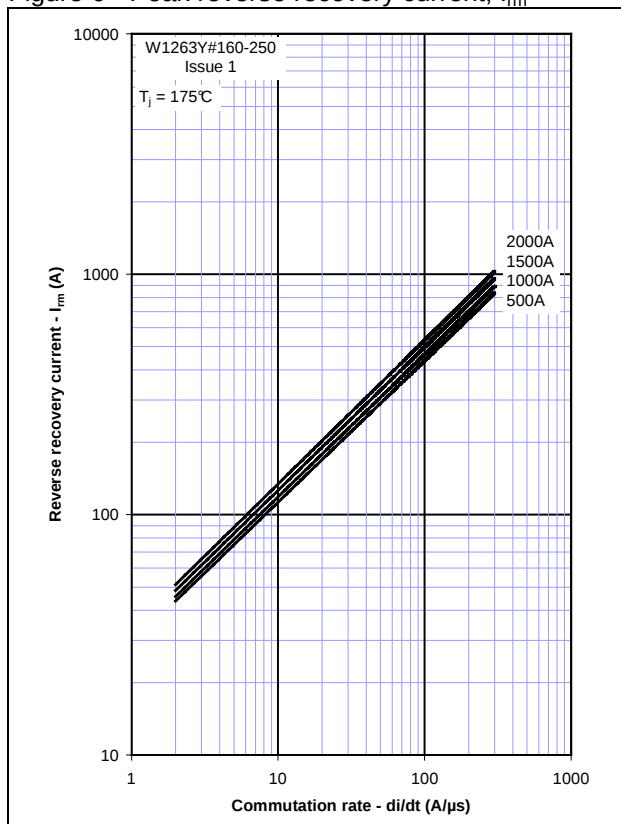
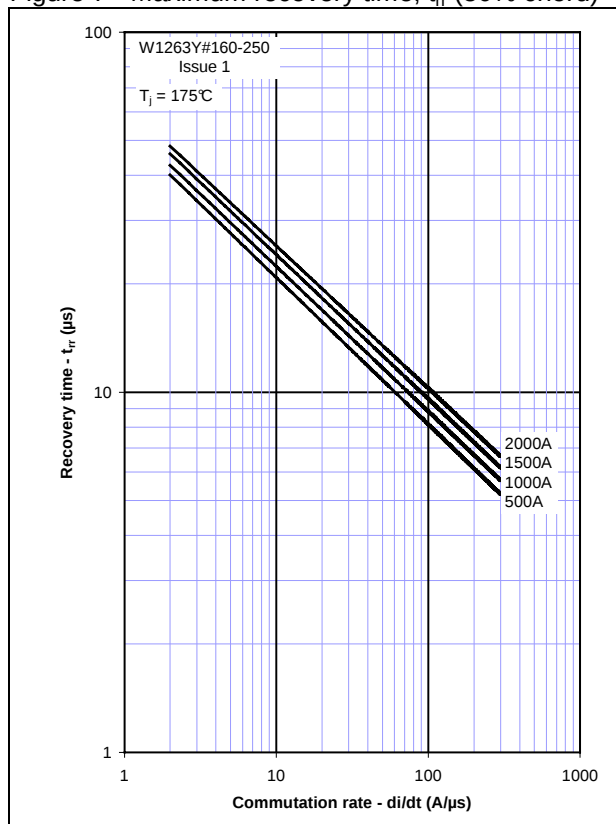
Figure 4 - Total recovered charge, Q_{rr} Figure 5 - Recovered charge, Q_{ra} (50% chord)Figure 6 - Peak reverse recovery current, I_{rm} Figure 7 - Maximum recovery time, t_{rr} (50% chord)

Figure 8 – Forward current vs. Power dissipation – Double Side Cooled

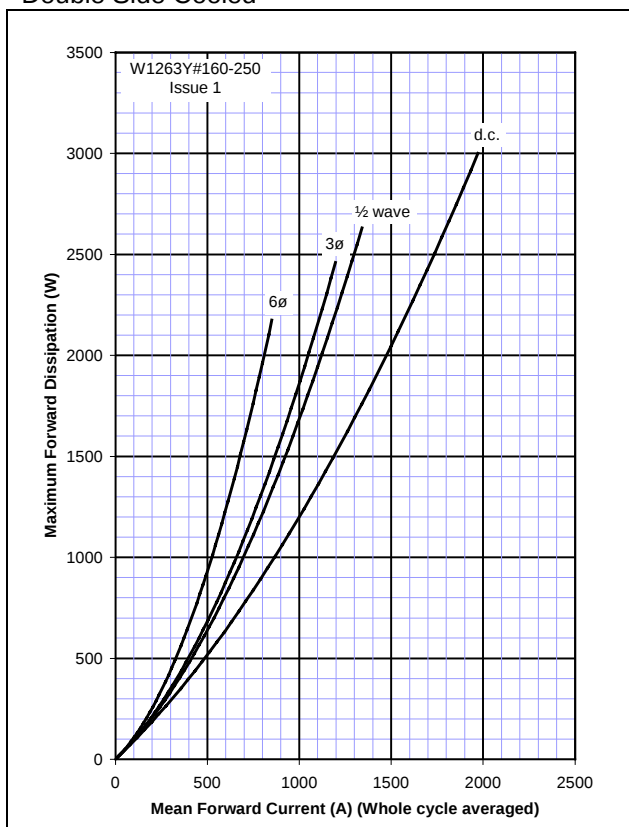


Figure 9 – Forward current vs. Heatsink temperature - Double Side Cooled

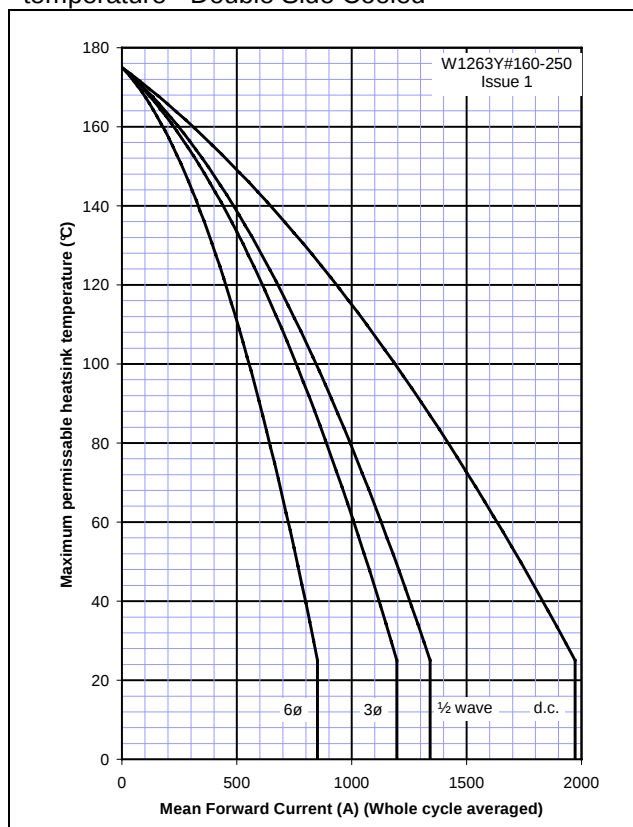


Figure 10 – Forward current vs. Power dissipation – Single Side Cooled

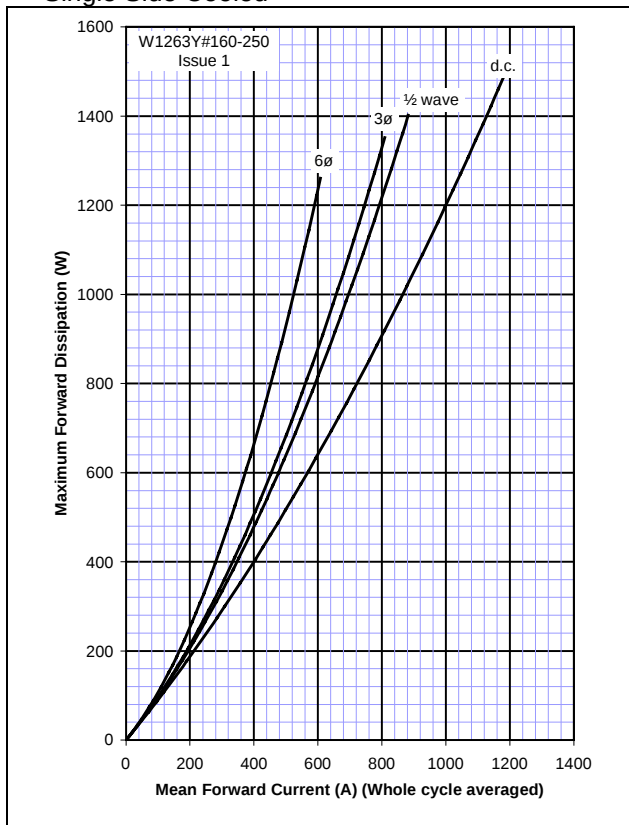
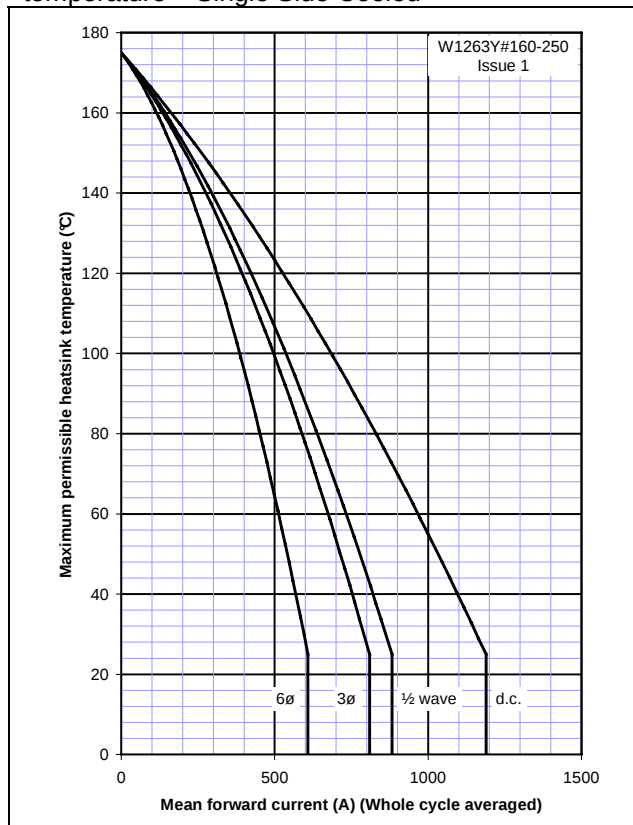
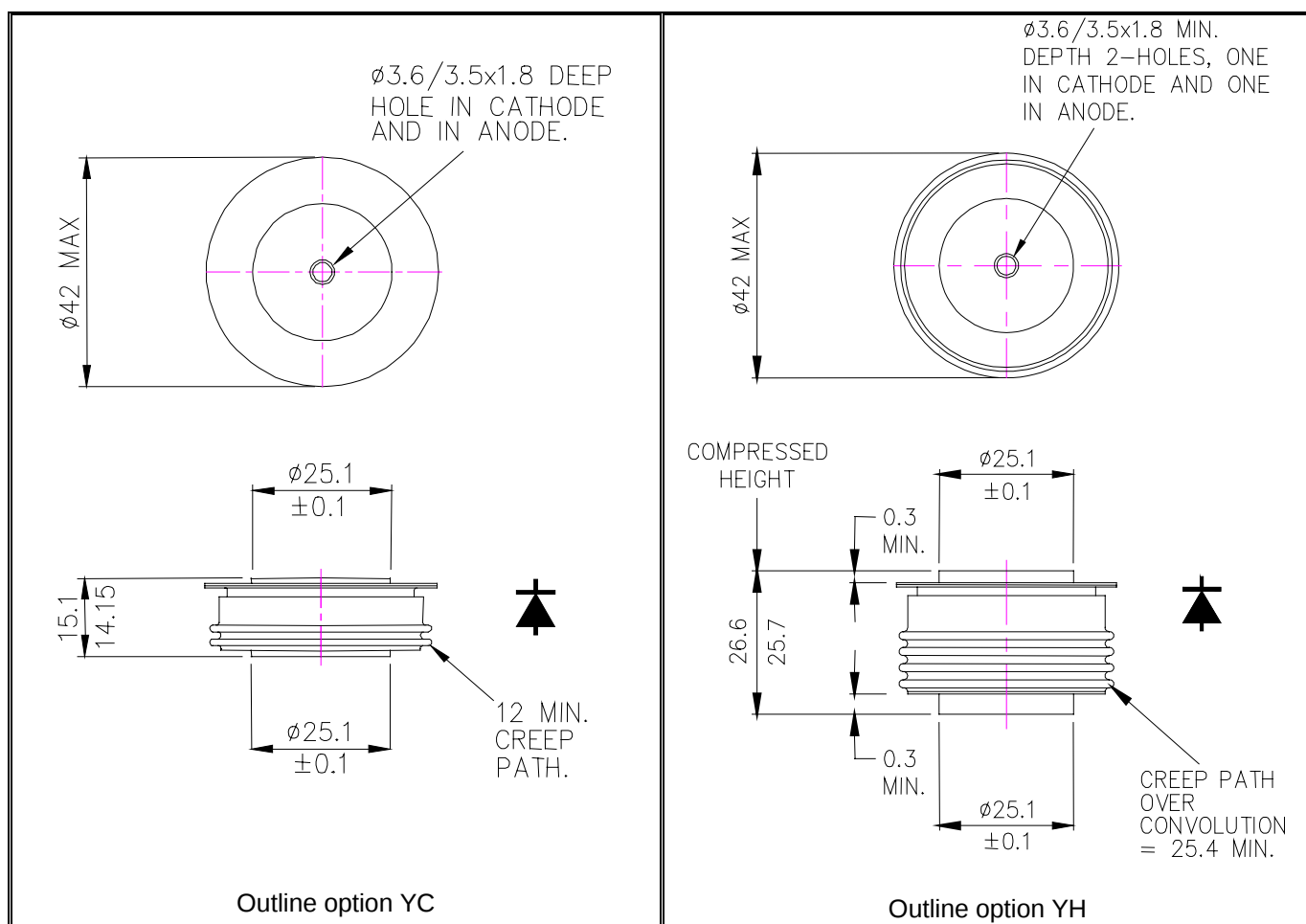


Figure 11 – Forward current vs. Heatsink temperature – Single Side Cooled



Outline Drawing & Ordering Information**ORDERING INFORMATION**

(Please quote 10 digit code as below)

W1263	Y#	◆◆	0
Fixed Type Code	Fixed outline code YC = 15.1mm Clamp Height YH = 26.6mm Clamp Height	Voltage code $V_{DRM}/100$ 16-25	Fixed code

Order code: W1263YH250 – 2500V V_{RRM} , 26.6mm clamp height capsule.**IXYS Semiconductor GmbH**

Edisonstraße 15
D-68623 Lampertheim
Tel: +49 6206 503-0
Fax: +49 6206 503-627
E-mail: marcom@ixys.de

WESTCODE
An IXYS Company

IXYS Corporation

3540 Bassett Street
Santa Clara CA 95054 USA
Tel: +1 (408) 982 0700
Fax: +1 (408) 496 0670
E-mail: sales@ixys.net

www.westcode.comwww.ixys.com**Westcode Semiconductors Ltd**

Langley Park Way, Langley Park,
Chippenham, Wiltshire SN15 1GE.
Tel: +44 (0)1249 444524
Fax: +44 (0)1249 659448
E-mail: WSL.sales@westcode.com

Westcode Semiconductors Inc

3270 Cherry Avenue
Long Beach CA 90807 USA
Tel: +1 (562) 595 6971
Fax: +1 (562) 595 8182
E-mail: WSI.sales@westcode.com

The information contained herein is confidential and is protected by Copyright. The information may not be used or disclosed except with the written permission of and in the manner permitted by the proprietors Westcode Semiconductors Ltd.

© Westcode Semiconductors Ltd.

In the interest of product improvement, Westcode reserves the right to change specifications at any time without prior notice.

Devices with a suffix code (2-letter, 3-letter or letter/digit/letter combination) added to their generic code are not necessarily subject to the conditions and limits contained in this report.